

# Digital Transistors (BRT) R1 = 100 k $\Omega$ , R2 = 100 k $\Omega$

NPN Transistors with Monolithic Bias Resistor Network

# MUN2236, MMUN2236L, MUN5236, DTC115EE, DTC115EM3

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### **Features**

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

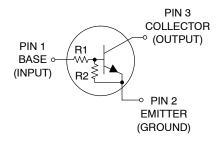
#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

| Rating                         | Symbol               | Max | Unit |
|--------------------------------|----------------------|-----|------|
| Collector-Base Voltage         | $V_{CBO}$            | 50  | Vdc  |
| Collector-Emitter Voltage      | $V_{CEO}$            | 50  | Vdc  |
| Collector Current - Continuous | Ic                   | 100 | mAdc |
| Input Forward Voltage          | V <sub>IN(fwd)</sub> | 40  | Vdc  |
| Input Reverse Voltage          | V <sub>IN(rev)</sub> | 10  | Vdc  |

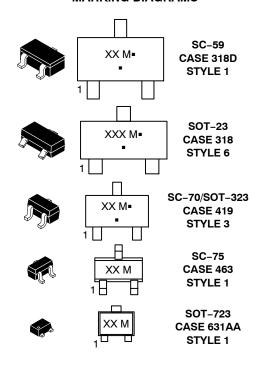
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1

#### **PIN CONNECTIONS**



#### **MARKING DIAGRAMS**



XXX = Specific Device Code

M = Date Code\*

• Pb-Free Package

(Note: Microdot may be in either location)

## **ORDERING INFORMATION**

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

<sup>\*</sup>Date Code orientation may vary depending upon manufacturing location.

**Table 1. ORDERING INFORMATION** 

| Device                         | Part Marking | Package                    | Shipping <sup>†</sup> |
|--------------------------------|--------------|----------------------------|-----------------------|
| NSVMUN2236T1G*                 | 8N           | SC-59<br>(Pb-Free)         | 3000 / Tape & Reel    |
| MMUN2236LT1G, NSVMMUN2236LT1G* | AA5          | SOT-23<br>(Pb-Free)        | 3000 / Tape & Reel    |
| MUN5236T1G, NSVMUN5236T1G*     | 8N           | SC-70/SOT-323<br>(Pb-Free) | 3000 / Tape & Reel    |
| DTC115EET1G                    | 8N           | SC-75<br>(Pb-Free)         | 3000 / Tape & Reel    |
| DTC115EM3T5G                   | 8N           | SOT-723<br>(Pb-Free)       | 8000 / Tape & Reel    |

### **DISCONTINUED** (Note 1)

| MUN2236T1G | 8N | SC-59<br>(Pb-Free) | 3000 / Tape & Reel |
|------------|----|--------------------|--------------------|
|            |    | (Fb-Flee)          |                    |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>1.</sup> DISCONTINUED: This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.

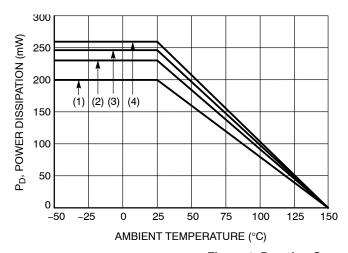


Figure 1. Derating Curve

- (1) SC-75 and SC-70/SOT323; Minimum Pad
- (2) SC-59; Minimum Pad
- (3) SOT-23; Minimum Pad
- (4) SOT-723; Minimum Pad

<sup>\*</sup>NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

**Table 2. THERMAL CHARACTERISTICS** 

| Characteristic  |  | Symbol                            | Max                      | Unit        |
|---|--|-----------------------------------|--------------------------|-------------|
| THERMAL CHARACTERISTICS (SC-59) (MUN2236)                               |  |                                   | •                        |             |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C          | (Note 2)<br>(Note 3)<br>(Note 2)<br>(Note 3) | P <sub>D</sub>                    | 230<br>338<br>1.8<br>2.7 | mW<br>mW/°C |
| Thermal Resistance,<br>Junction to Ambient                              | (Note 2)<br>(Note 3)                         | $R_{	hetaJA}$                     | 540<br>370               | °C/W        |
| Thermal Resistance,<br>Junction to Lead                                 | (Note 2)<br>(Note 3)                         | $R_{	hetaJL}$                     | 264<br>287               | °C/W        |
| Junction and Storage Temperature Range                                  |  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150              | °C          |
| THERMAL CHARACTERISTICS (SOT-23) (MMUN2236L)                            |  |                                   | •                        |             |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C          | (Note 2)<br>(Note 3)<br>(Note 2)<br>(Note 3) | P <sub>D</sub>                    | 246<br>400<br>2.0<br>3.2 | mW<br>mW/°C |
| Thermal Resistance,<br>Junction to Ambient                              | (Note 1)<br>(Note 3)                         | $R_{	heta JA}$                    | 508<br>311               | °C/W        |
| Thermal Resistance,<br>Junction to Lead                                 | (Note 2)<br>(Note 3)                         | $R_{	hetaJL}$                     | 174<br>208               | °C/W        |
| Junction and Storage Temperature Range                                  |  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150              | °C          |
| THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5236)                       |  |                                   |                          |             |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$ | (Note 2)<br>(Note 3)<br>(Note 2)<br>(Note 3) | P <sub>D</sub>                    | 202<br>310<br>1.6<br>2.5 | mW<br>mW/°C |
| Thermal Resistance, Junction to Ambient                                 | (Note 2)<br>(Note 3)                         | $R_{	heta JA}$                    | 618<br>403               | °C/W        |
| Thermal Resistance,<br>Junction to Lead                                 | (Note 2)<br>(Note 3)                         | $R_{	hetaJL}$                     | 280<br>332               | °C/W        |
| Junction and Storage Temperature Range                                  |  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150              | °C          |
| THERMAL CHARACTERISTICS (SC-75) (DTC115EE)                              |  |                                   |                          |             |
| Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C          | (Note 2)<br>(Note 3)<br>(Note 2)<br>(Note 3) | P <sub>D</sub>                    | 200<br>300<br>1.6<br>2.4 | mW<br>mW/°C |
| Thermal Resistance,<br>Junction to Ambient                              | (Note 2)<br>(Note 3)                         | $R_{	hetaJA}$                     | 600<br>400               | °C/W        |
| Junction and Storage Temperature Range                                  |  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150              | °C          |
| THERMAL CHARACTERISTICS (SOT-723) (DTC115EM3)                           |  | _                                 |                          |             |
| Total Device Dissipation  T <sub>A</sub> = 25°C  Derate above 25°C      | (Note 2)<br>(Note 3)<br>(Note 2)<br>(Note 3) | P <sub>D</sub>                    | 260<br>600<br>2.0<br>4.8 | mW<br>mW/°C |
| Thermal Resistance,<br>Junction to Ambient                              | (Note 2)<br>(Note 3)                         | $R_{	heta JA}$                    | 480<br>205               | °C/W        |
| Junction and Storage Temperature Range                                  |  | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150              | °C          |

FR-4 @ Minimum Pad.
 FR-4 @ 1.0 x 1.0 Inch Pad.

Table 3. ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, unless otherwise noted)

| Characteristic   | Symbol                         | Min | Тур | Max  | Unit |
|--|--------------------------------|-----|-----|------|------|
| OFF CHARACTERISTICS  | •                              | •   | •   |      |      |
| Collector-Base Cutoff Current (V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0)                       | I <sub>CBO</sub>               | _   | _   | 100  | nAdc |
| Collector-Emitter Cutoff Current (V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0)                    | I <sub>CEO</sub>               | _   | -   | 500  | nAdc |
| Emitter-Base Cutoff Current (V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0)                        | I <sub>EBO</sub>               | _   | -   | 0.05 | mAdc |
| Collector–Base Breakdown Voltage ( $I_C = 10 \mu A, I_E = 0$ )                                   | V <sub>(BR)</sub> CBO          | 50  | -   | -    | Vdc  |
| Collector-Emitter Breakdown Voltage (Note 4) (I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)       | V <sub>(BR)</sub> CEO          | 50  | -   | -    | Vdc  |
| ON CHARACTERISTICS   |                                |     |     |      |      |
| DC Current Gain (Note 4)<br>(I <sub>C</sub> = 5.0 mA, V <sub>CE</sub> = 10 V)                    | h <sub>FE</sub>                | 80  | 150 | -    |      |
| Collector-Emitter Saturation Voltage (Note 4) (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.3 mA)  | V <sub>CE(sat)</sub>           | _   | -   | 0.25 | Vdc  |
| Input Voltage (off)<br>(V <sub>CE</sub> = 5.0 V, I <sub>C</sub> = 100 μA)                        | V <sub>i(off)</sub>            | _   | 1.2 | 0.5  | Vdc  |
| Input Voltage (on)<br>(V <sub>CE</sub> = 0.3 V, I <sub>C</sub> = 1.0 mA)                         | V <sub>i(on)</sub>             | 3.0 | 1.7 | -    | Vdc  |
| Output Voltage (on) $(V_{CC} = 5.0 \text{ V}, V_B = 5.5 \text{ V}, R_L = 1.0 \text{ k}\Omega)$   | V <sub>OL</sub>                | -   | -   | 0.2  | Vdc  |
| Output Voltage (off) $(V_{CC} = 5.0 \text{ V}, V_B = 0.25 \text{ V}, R_L = 1.0 \text{ k}\Omega)$ | V <sub>OH</sub>                | 4.9 | -   | -    | Vdc  |
| Input Resistor   | R1                             | 70  | 100 | 130  | kΩ   |
| Resistor Ratio   | R <sub>1</sub> /R <sub>2</sub> | 0.8 | 1.0 | 1.2  |      |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle ≤ 2%.

# TYPICAL CHARACTERISTICS MUN2236, MMUN2236L, MUN5236, NSVMUN5236, DTC115EE, DTC115EM3

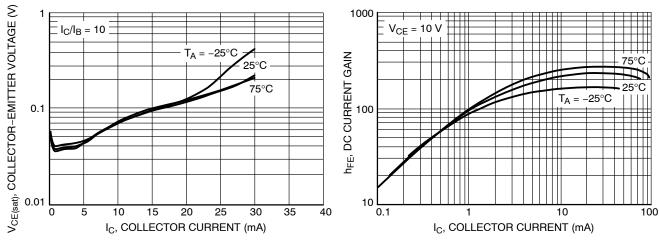


Figure 2. V<sub>CE(sat)</sub> versus I<sub>C</sub>

Figure 3. DC Current Gain

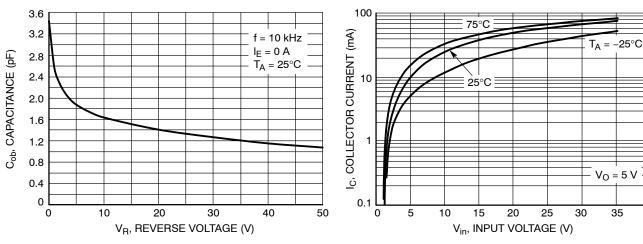


Figure 4. Output Capacitance

Figure 5. Output Current versus Input Voltage

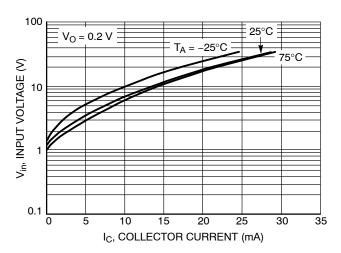


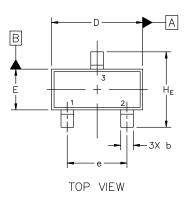
Figure 6. Input Voltage versus Output Current

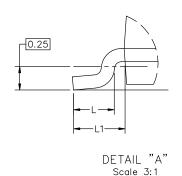


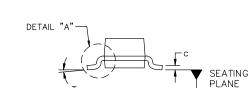


#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

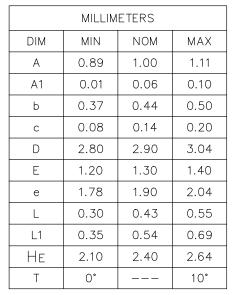
**DATE 14 AUG 2024** 







END VIEW



#### NOTES:

- DIMENSIONING AND TOLERANCING 1. PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS:
- MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.



SIDE VIEW

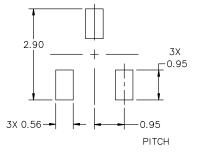


XXX = Specific Device Code

= Date Code

= Pb-Free Package

<sup>\*</sup>This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.



C

### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **STYLES ON PAGE 2**

| DOCUMENT NUMBER: | 98ASB42226B Electronic versions are uncontrolled except when accessed directly from<br>Printed versions are uncontrolled except when stamped "CONTROLLED |              |             |  |
|------------------|--|--------------|-------------|--|
| DESCRIPTION:     | SOT-23 (TO-236) 2.90x1.3   | 0x1.00 1.90P | PAGE 1 OF 2 |  |

onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries, onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

## SOT-23 (TO-236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

| STYLE 1 THRU 5:<br>CANCELLED                            | STYLE 6:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR | STYLE 7:<br>PIN 1. EMITTER<br>2. BASE<br>3. COLLECTOR | STYLE 8:<br>PIN 1. ANODE<br>2. NO CONNECTION<br>3. CATHODE | 1                |                  |
|---|---|---|--|------------------|------------------|
| STYLE 9:  | STYLE 10:   | STYLE 11:   | STYLE 12: PIN 1. CATHODE 2. CATHODE 3. ANODE               | STYLE 13:        | STYLE 14:        |
| PIN 1. ANODE  | PIN 1. DRAIN  | PIN 1. ANODE  |  | PIN 1. SOURCE    | PIN 1. CATHODE   |
| 2. ANODE  | 2. SOURCE   | 2. CATHODE  |  | 2. DRAIN         | 2. GATE          |
| 3. CATHODE  | 3. GATE   | 3. CATHODE-ANODE                                      |  | 3. GATE          | 3. ANODE         |
| STYLE 15:   | STYLE 16:   | STYLE 17:   | STYLE 18:  | STYLE 19:        | STYLE 20:        |
| PIN 1. GATE   | PIN 1. ANODE  | PIN 1. NO CONNECTION                                  | PIN 1. NO CONNECTION                                       | N PIN 1. CATHODE | PIN 1. CATHODE   |
| 2. CATHODE  | 2. CATHODE  | 2. ANODE  | 2. CATHODE   | 2. ANODE         | 2. ANODE         |
| 3. ANODE  | 3. CATHODE  | 3. CATHODE  | 3. ANODE   | 3. CATHODE-ANODE | 3. GATE          |
| STYLE 21:   | STYLE 22:   | STYLE 23:   | STYLE 24:  | STYLE 25:        | STYLE 26:        |
| PIN 1. GATE   | PIN 1. RETURN   | PIN 1. ANODE  | PIN 1. GATE  | PIN 1. ANODE     | PIN 1. CATHODE   |
| 2. SOURCE   | 2. OUTPUT   | 2. ANODE  | 2. DRAIN   | 2. CATHODE       | 2. ANODE         |
| 3. DRAIN  | 3. INPUT  | 3. CATHODE  | 3. SOURCE  | 3. GATE          | 3. NO CONNECTION |
| STYLE 27:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE | STYLE 28:<br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE     |   |  |                  |                  |

| DOCUMENT NUMBER: | 98ASB42226B              | Electronic versions are uncontrolled except when accessed directly from the Document Repo<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |  |  |
|------------------|--------------------------|--|--|--|
| DESCRIPTION:     | SOT-23 (TO-236) 2.90x1.3 | SOT-23 (TO-236) 2.90x1.30x1.00 1.90P   |  |  |

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





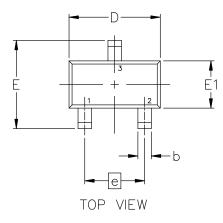
#### SC-59-3 2.90x1.50x1.15, 1.90P CASE 318D ISSUE J

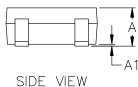
**DATE 15 FEB 2024** 

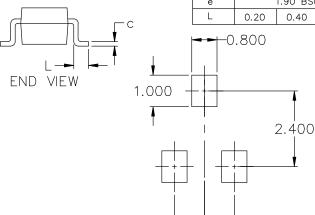
#### NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- 2. ALL DIMENSION ARE IN MILLIMETERS.

|     | MILLIMETERS |      |      |  |
|-----|-------------|------|------|--|
| DIM | MIN.        | NOM. | MAX. |  |
| Α   | 1.00        | 1.15 | 1.30 |  |
| A1  | 0.01        | 0.06 | 0.10 |  |
| b   | 0.35        | 0.43 | 0.50 |  |
| С   | 0.09        | 0.14 | 0.18 |  |
| D   | 2.70        | 2.90 | 3.10 |  |
| E   | 2.50        | 2.80 | 3.00 |  |
| E1  | 1.30        | 1.50 | 1.70 |  |
| е   | 1.90 BSC    |      |      |  |
| L   | 0.20        | 0.40 | 0.60 |  |







0.950

# GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

M = Date Code

= Pb-Free Package\*

(\*Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

#### RECOMMENDED MOUNTING FOOTPRINT\*

\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

| STYLE 1:                    | STYLE 2:                  | STYLE 3:                  |
|-----------------------------|---------------------------|---------------------------|
| PIN 1. BASE                 | PIN 1. ANODE              | PIN 1. ANODE              |
| 2. EMITTER                  | 2. N.C.                   | 2. ANODE                  |
| <ol><li>COLLECTOR</li></ol> | <ol><li>CATHODE</li></ol> | <ol><li>CATHODE</li></ol> |

| STYLE 4:       | STYLE 5:       | STYLE 6:                        |
|----------------|----------------|---------------------------------|
| PIN 1. CATHODE | PIN 1. CATHODE | PIN 1. ANODE                    |
| 2. N.C.        | 2. CATHODE     | 2. CATHODE                      |
| 3. ANODE       | 3. ANODE       | <ol><li>ANODE/CATHODE</li></ol> |

| DOCUMENT NUMBER: | 98ASB42664B               | Electronic versions are uncontrolled except when accessed directly from the Document Re<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |  |
|------------------|---------------------------|--|--|
| DESCRIPTION:     | SC-59-3 2.90x1.50x1.15, 1 | SC-59-3 2.90x1.50x1.15, 1.90P  |  |

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.







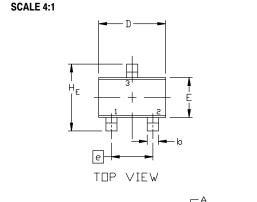
SC-70 (SOT-323) CASE 419 ISSUE R

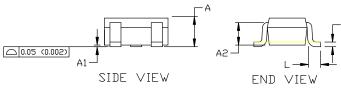
**DATE 11 OCT 2022** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

|     | MILLIMETERS |                    |      |          | INCHES |       |
|-----|-------------|--------------------|------|----------|--------|-------|
| DIM | MIN.        | N□M.               | MAX. | MIN.     | N□M.   | MAX.  |
| Α   | 0.80        | 0.90               | 1.00 | 0.032    | 0.035  | 0.040 |
| A1  | 0.00        | 0.05               | 0.10 | 0.000    | 0.002  | 0.004 |
| A2  |             | 0.70 REF 0.028 BSC |      | C        |        |       |
| b   | 0.30        | 0.35               | 0.40 | 0.012    | 0.014  | 0.016 |
| С   | 0.10        | 0.18               | 0.25 | 0.004    | 0.007  | 0.010 |
| D   | 1.80        | 2.00               | 2.20 | 0.071    | 0.080  | 0.087 |
| E   | 1.15        | 1.24               | 1.35 | 0.045    | 0.049  | 0.053 |
| е   | 1.20        | 1.30               | 1.40 | 0.047    | 0.051  | 0.055 |
| e1  | 0.65 BSC    |                    |      | 0.026 BS | C      |       |
| L   | 0.20        | 0.38               | 0.56 | 0.008    | 0.015  | 0.022 |
| HE  | 2.00        | 2.10               | 2.40 | 0.079    | 0.083  | 0.095 |





# GENERIC MARKING DIAGRAM

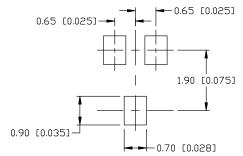


XX = Specific Device Code

M = Date Code

■ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



For additional information on our Pb-Free strategy and soldering details, please download the ID Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

SOLDERING FOOTPRINT

| STYLE 1:<br>CANCELLED       | STYLE 2:<br>PIN 1. ANODE<br>2. N.C.<br>3. CATHODE | STYLE 3:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR | STYLE 4:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. ANODE | STYLE 5:<br>PIN 1. ANODE<br>2. ANODE<br>3. CATHODE |                           |
|-----------------------------|---|---|--|--|---------------------------|
| STYLE 6:                    | STYLE 7:  | STYLE 8:  | STYLE 9:   | STYLE 10:  | STYLE 11:                 |
| PIN 1. EMITTER              | PIN 1. BASE                                       | PIN 1. GATE   | PIN 1. ANODE   | PIN 1. CATHODE                                     | PIN 1. CATHODE            |
| 2. BASE                     | 2. EMITTER  | 2. SOURCE   | 2. CATHODE   | 2. ANODE   | <ol><li>CATHODE</li></ol> |
| <ol><li>COLLECTOR</li></ol> | <ol><li>COLLECTOR</li></ol>                       | 3. DRAIN  | <ol><li>CATHODE-ANODE</li></ol>                      | 3. ANODE-CATHODE                                   | <ol><li>CATHODE</li></ol> |

| DOCUMENT NUMBER: | 98ASB42819B     | Electronic versions are uncontrolled except when accessed directly from the Document Reposit<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |  |
|------------------|-----------------|---|-------------|--|
| DESCRIPTION:     | SC-70 (SOT-323) |   | PAGE 1 OF 1 |  |

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.



### SC75-3 1.60x0.80x0.80, 1.00P

**CASE 463 ISSUE H** 

**DATE 01 FEB 2024** 

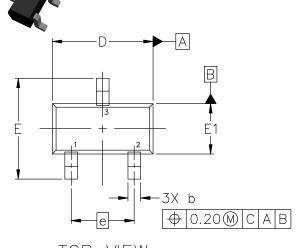


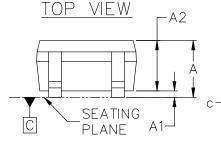
- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS.

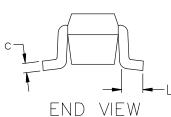
| DIM  | MILLIMETERS |      |      |  |  |
|------|-------------|------|------|--|--|
| INII | MIN.        | NOM. | MAX. |  |  |
| А    | 0.70        | 0.80 | 0.90 |  |  |
| A1   | 0.00        | 0.05 | 0.10 |  |  |
| A2   | 0.80 REF.   |      |      |  |  |
| b    | 0.15        | 0.20 | 0.30 |  |  |
| С    | 0.10        | 0.15 | 0.25 |  |  |
| D    | 1.55        | 1.60 | 1.65 |  |  |
| Е    | 1.50        | 1.60 | 1.70 |  |  |
| E1   | 0.70        | 0.80 | 0.90 |  |  |
| е    | 1.00 BSC    |      |      |  |  |
| L    | 0.10        | 0.15 | 0.20 |  |  |

-0.356

0.787







SIDE VIEW

### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code

Μ = Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

| STYLE 1:    |  |
|-------------|--|
| PIN 1. BASE |  |
| 2. EMITTER  |  |

3 COLLECTOR

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE STYLE 3: PIN 1. ANODE 2. ANODE 3 CATHODE

1.803

0.508

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

1.000

RECOMMENDED MOUNTING FOOTPRINT\*

| STYLE 4:                  |
|---------------------------|
| PIN 1. CATHODE            |
| <ol><li>CATHODE</li></ol> |
| <ol><li>ANODE</li></ol>   |

STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN

Electronic versions are uncontrolled except when accessed directly from the Document Repository. **DOCUMENT NUMBER:** 98ASB15184C Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DESCRIPTION:** SC75-3 1.60x0.80x0.80, 1.00P PAGE 1 OF 1

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





#### SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

**DATE 24 JAN 2024** 

MAX.

0.55

0.27

0.37

0.17

MILLIMETERS

 $N\square M$ .

0.50

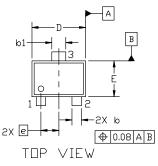
0.21

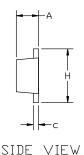
0.31

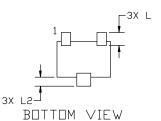
0.12

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.







|              | _    |          |          |      |  |  |  |
|--------------|------|----------|----------|------|--|--|--|
|              | D    | 1.15     | 1.20     | 1.25 |  |  |  |
|              | E    | 0.75     | 0.80     | 0.85 |  |  |  |
|              | u    |          | 0.40 BSC |      |  |  |  |
|              | I    | 1.15     | 1.20     | 1.25 |  |  |  |
|              |      | 0.29 REF |          |      |  |  |  |
|              | L2   | 0.15     | 0.20     | 0.25 |  |  |  |
| 2X<br>(AGE — | 0.27 | PIT      |          |      |  |  |  |

MIN.

0.45

0.15

0.25

0.07

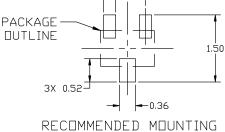
DIM

Α

b

b1

 $\subset$ 



\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

FOOTPRINT

### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

| STYLE 1:                    | STYLE 2:                  | STYLE 3:                  | STYLE 4:                  | STYLE 5:                 |
|-----------------------------|---------------------------|---------------------------|---------------------------|--------------------------|
| PIN 1. BASE                 | PIN 1. ANODE              | PIN 1. ANODE              | PIN 1. CATHODE            | PIN 1. GATE              |
| <ol><li>EMITTER</li></ol>   | 2. N/C                    | 2. ANODE                  | <ol><li>CATHODE</li></ol> | <ol><li>SOURCE</li></ol> |
| <ol><li>COLLECTOR</li></ol> | <ol><li>CATHODE</li></ol> | <ol><li>CATHODE</li></ol> | <ol><li>ANODE</li></ol>   | <ol><li>DRAIN</li></ol>  |

| DOCUMENT NUMBER: | 98AON12989D                   | Electronic versions are uncontrolled except when accessed directly from the Document Reposit<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |             |  |
|------------------|-------------------------------|---|-------------|--|
| DESCRIPTION:     | SOT-723 1.20x0.80x0.50, 0.40P |   | PAGE 1 OF 1 |  |

onsemi and Onsemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries, onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales